

Quarterly Reliability Monitoring Results

Quarters: Q1/2021 to Q4/2021

Based on structural similarity

Supplier Nexperia B.V. Name of Laboratory Assembly reliability labs Based on AEC-Q101 Test		User Part Number BC857BM Part Description										
								Nexperia DHAM Small Signal Bipolar Transistor				
								MCD package				
		Test Conditions	Duration	# Lots	# Quantity	# Rejects						
			TEST									
			Pre- and Post-Stress									
# E1	Electrical Test	Tamb = 25 °C	N/A	see below	all parts	see below						
		JESD22-A113										
		Bake Tamb = 125 °C	24 hours									
	PC	Soak Tamb = 85 °C, RH = 85%	168 hours									
# A1	Preconditioning	Reflow soldering	3 cycles	208	16640	0						
		MIL-STD-750-1										
	HTRB	M1039 Method A										
	High Temperature Reverse	Tj = Tjmax, Vr = 100% of max. datasheet										
# B1	Bias	reverse voltage	1000 hours	202	16160	0						
	TC	JESD22-A104										
# A4	Temperature Cycling	-65 °C to Tjmax, not to exceed 150°C	1000 cycles	52	4160	0						
		JESD22-A102										
	AC	Tamb = 121 °C, RH = 100 %										
# A3 alt	Autoclave	Pressure = 205 kPa (29.7 psia)	96 hours	52	4160	0						
		JECD22 A101										
	H3TRB	JESD22-A101 Tamb = 85 °C, RH = 85%, VR = 80 % of										
" AO II	High Humidity High Temperature Reverse Bias		10001		44.60							
# A2 alt	Temperature Reverse Bias		1000 hours	52	4160	0						
		MIL-STD-750 Method 1037										
	IOL	ton = toff, devices powered to insure ΔTj =				_						
# A5	Intermittent Operating Life	100 °C for 15000 cycles	1000 hours	52	4160	0						
	RSH	JESD22-A111										
# C8	Resistance to Solder Heat		10 s	2.2	n 2	n 2						
# C8	SD	200 0 2 3 0	10 5	n.a.	n.a.	n.a.						
# C10	Solderability	J-STD-002			1110	0						
# C10	30idel ability	J-31D-00Z		111	1110	0						

^[1] The maximum applied voltage is limited by test chamber set up and does not exceed 115V.

Calculation of FIT and MTTF

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, Test #B1)
Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

Wafer Fab	Technology	Quantity	Rejects	Failure Rate (FIT)	MTTF (hrs)
Nexperia	Small Signal Bipolar				
DHAM	Transistor	16160	0	0.26	3.81E+09

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